TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK372

For Audio Amplifier, Analog-Switch, Constant-Current and Impedance Converter Applications

- High breakdown voltage: $V_{GDS} = -40 \text{ V}$
- High input impedance: $I_{GSS} = -1.0 \text{ nA (max) (V}_{GS} = -30 \text{ V)}$
- Low RDS (ON): RDS (ON) = 20Ω (typ.) (IDSS = 15 mA)
- Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V_{GDS}	-40	V
Gate current	IG	10	mA
Drain power dissipation	P_{D}	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	−55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

0.55 MAX. 0.55 MAX. 1. DRAIN 2. GATE 3. SOURCE JEDEC JEITA TOSHIBA 2-4E1C

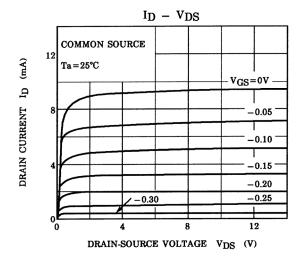
Weight: 0.13 g (typ.)

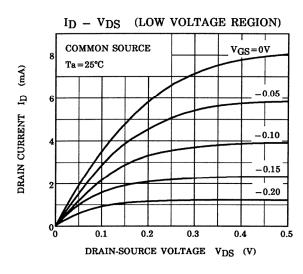
Electrical Characteristics (Ta = 25°C)

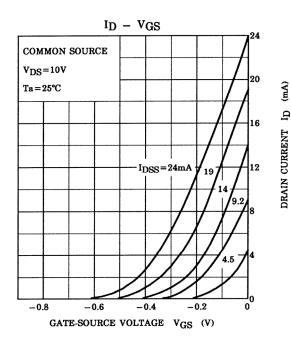
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = -30 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V _(BR) GDS	$V_{DS} = 0$, $I_G = -100 \mu A$	-40		_	V
Drain current	I _{DSS} (Note 1)	V _{DS} = 10 V, V _{GS} = 0	5.0		30	mA
Gate-source cut-off voltage	V _{GS} (OFF)	$V_{DS} = 10 \text{ V}, I_D = 0.1 \mu A$	-0.3	_	-1.2	٧
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz (Note 2)}$	25	60	_	mS
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	75	_	pF
Reverse transfer capacitance	C _{rss}	$V_{DG} = 10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	15	_	pF
Drain-source ON resistance	R _{DS (ON)}	$V_{DS} = 10 \text{ mV}, V_{GS} = 0$ (Note 2)	_	20	_	Ω

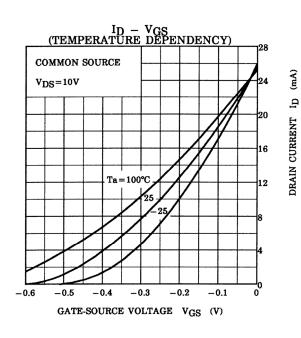
Note 1: IDSS classification GR: 5.0~10.0 mA, BL: 8.0~16.0 mA, V: 14.0~30.0 mA

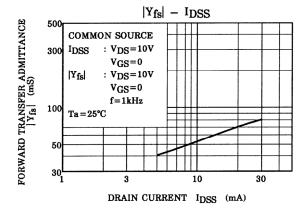
Note 2: Typical I_{DSS} rating = 15 mA

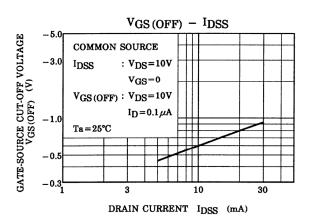




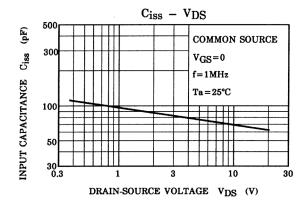


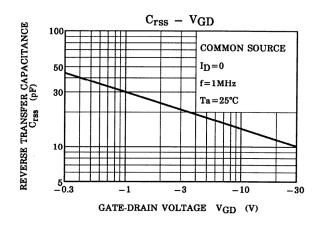


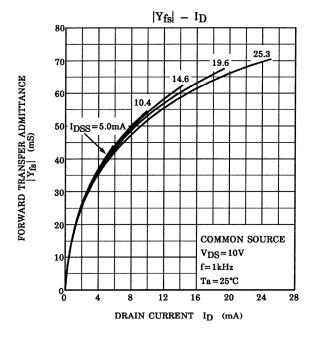


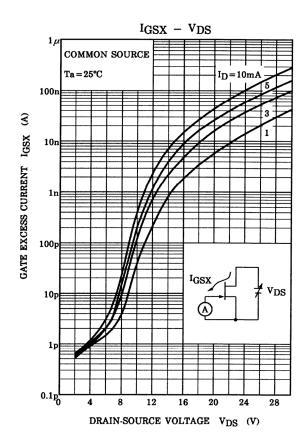


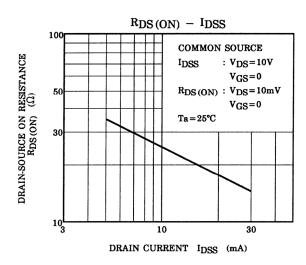
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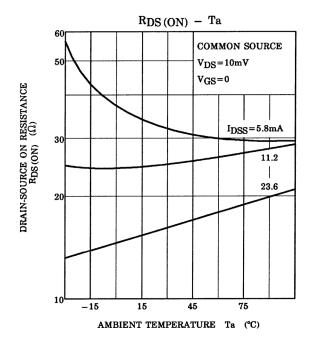


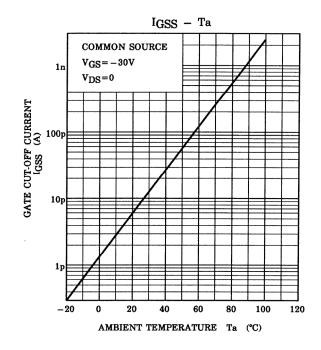


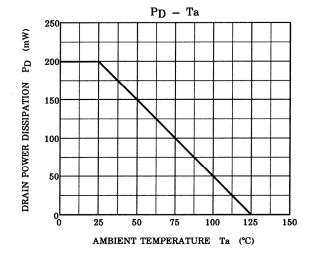




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20070701-EN GENERAL

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